

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
-30V	46mΩ@-10V	-5A
	65mΩ@-4.5V	

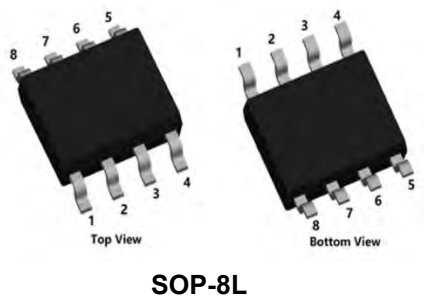
Feature

- Fast Switching
- Low Gate Charge and Rds on

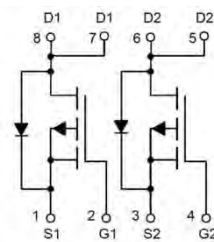
Applications

- Power Switching Application
- Hard switched and high frequency circuits
- Uninterruptible Power Supply

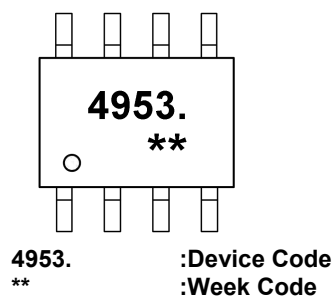
Package



Circuit Diagram



Marking



Order Information

Device	Package	Unit/Tape
IRF7316TRPBF-CN	SOP-8L	4000

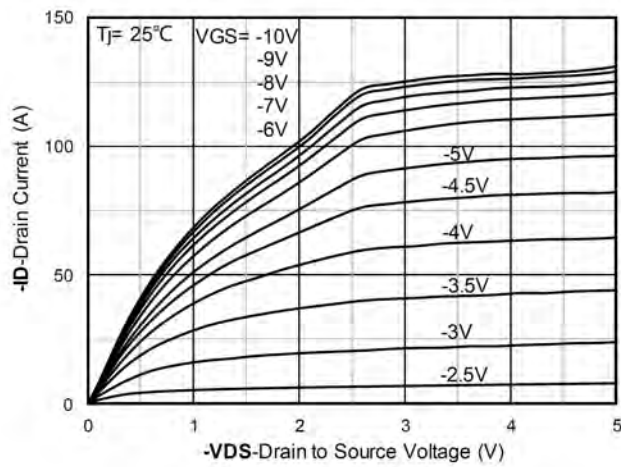
Absolute maximum ratings (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	-5	A
Pulsed Drain Current	I_{DM}	-20	A
Power Dissipation	P_D	1.1	W
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	113	°C/W
Storage Temperature Range	T_{STG}	-55 to 150	°C
Operating Junction Temperature Range	T_J	-55 to 150	°C

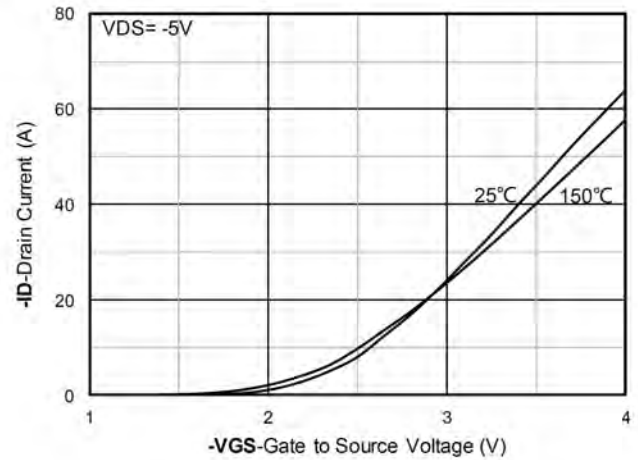
Electrical characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V , ID=-250uA	-30	-	-	V
Drain-Source Leakage Current	IDSS	VDS=-24V , VGS=0V	-	-	-1	uA
Gate-Source Leakage Current	IGSS	VGS=±20V , VDS=0V	-	-	±100	nA
Gate Threshold Voltage	VGS(th)	VGS=VDS , ID =-250uA	-1.0	-1.5	-2.5	V
Static Drain-Source On-Resistance	RDS(ON)	VGS=-10V , ID=-4.1A	-	46	60	mΩ
		VGS=-4.5V , ID=-3.0A	-	65	90	
Dynamic characteristics						
Input Capacitance	Ciss	VDS=-15V , VGS=0V , f=1MHz	-	463	-	pF
Output Capacitance	Coss		-	82	-	
Reverse Transfer Capacitance	Crss		-	68	-	
Total Gate Charge	Qg	VDS=-15V , VGS=-10V , ID=-5A	-	5.22	-	nC
Gate-Source Charge	Qgs		-	1.25	-	
Gate-Drain Charge	Qgd		-	2.3	-	
Switching Characteristics						
Turn-On Delay Time	Td(on)	VDD=-15V VGS=-10V , RG=6Ω, ID=-1A	-	18.4	-	nS
Rise Time	Tr		-	11.4	-	
Turn-Off Delay Time	Td(off)		-	39.4	-	
Fall Time	Tf		-	5.2	-	
Diode Characteristics						
Diode Forward Voltage	VSD	VGS=0V , IS=-1A	-	-	-1.2	V

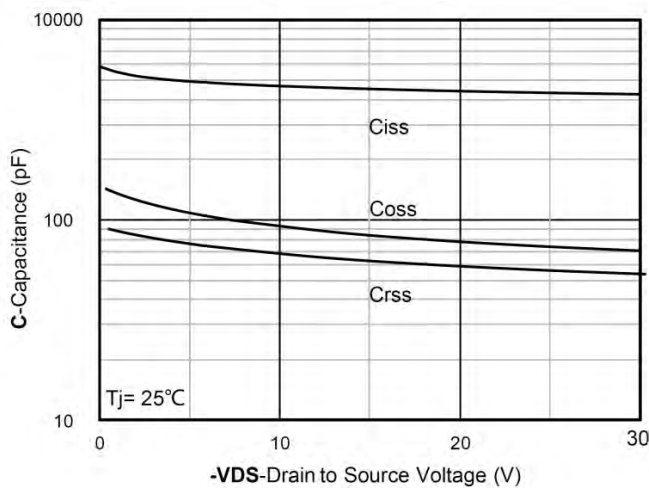
Typical Characteristics



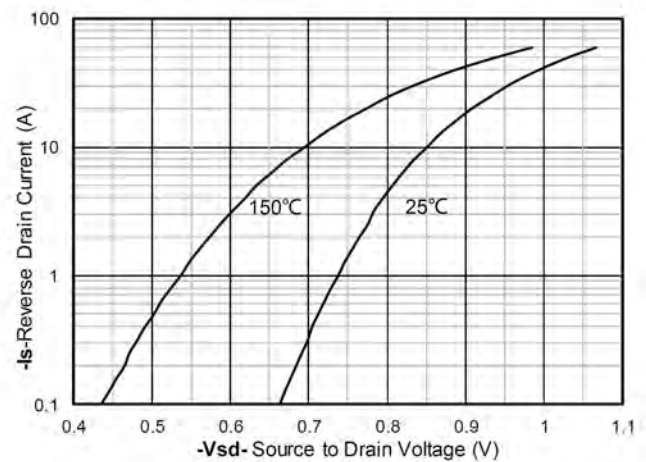
Output Characteristics



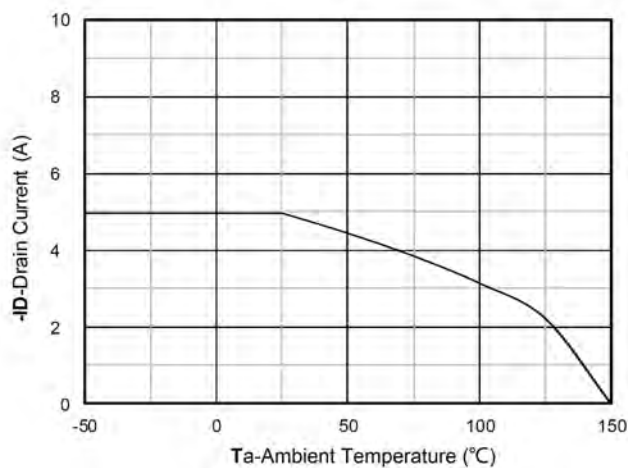
Transfer Characteristics



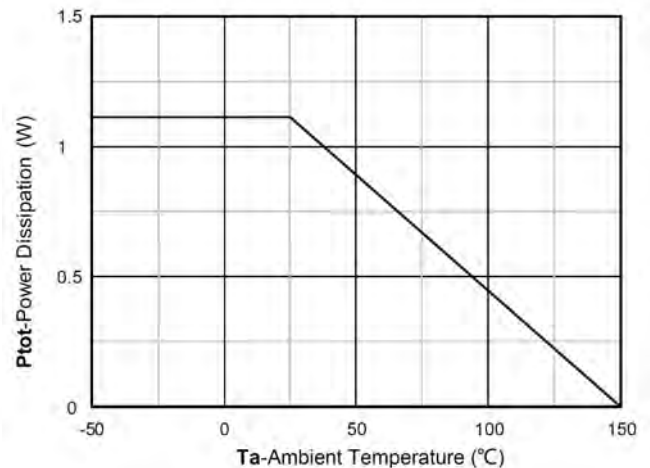
Capacitance Characteristics



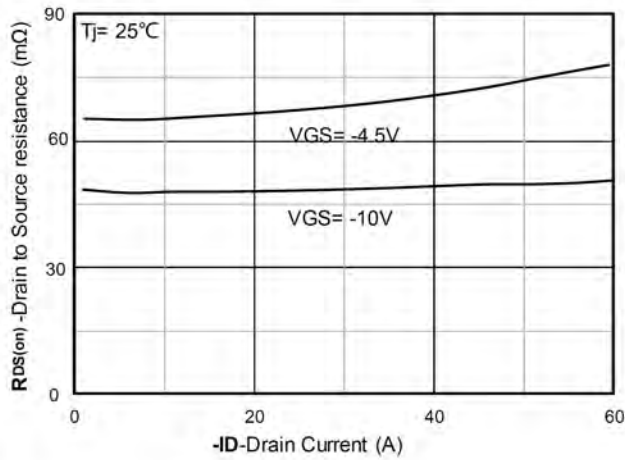
Forward characteristics of reverse diode



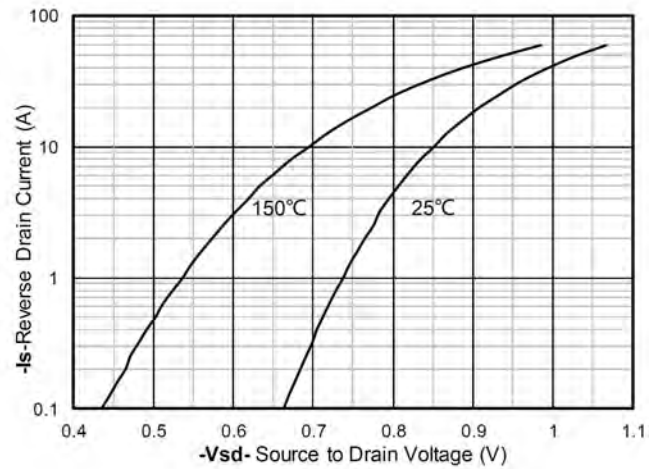
Current dissipation



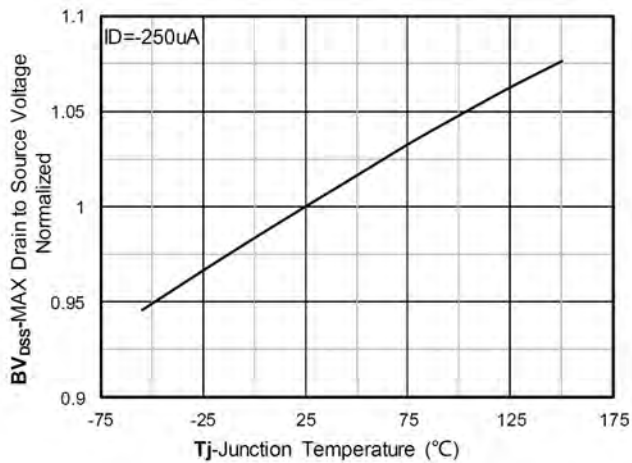
Power dissipation



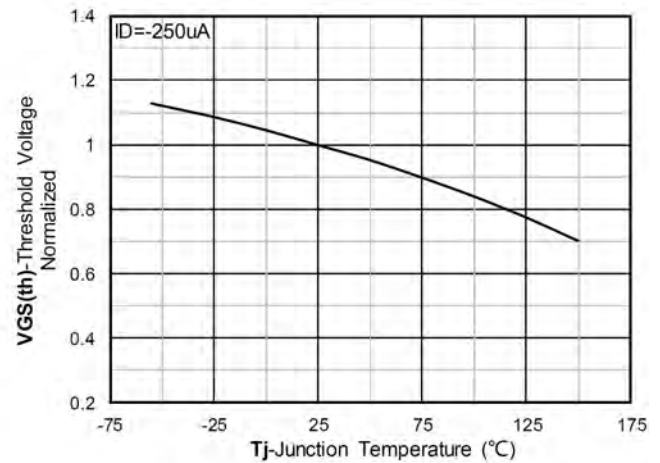
$R_{DS(on)}$ VS Drain Current



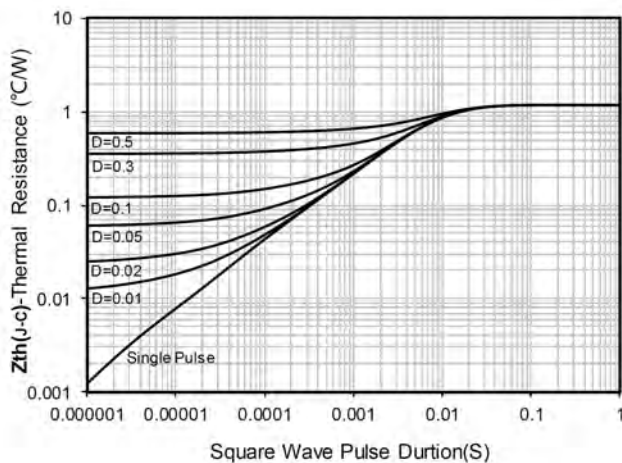
Forward characteristics of reverse diode



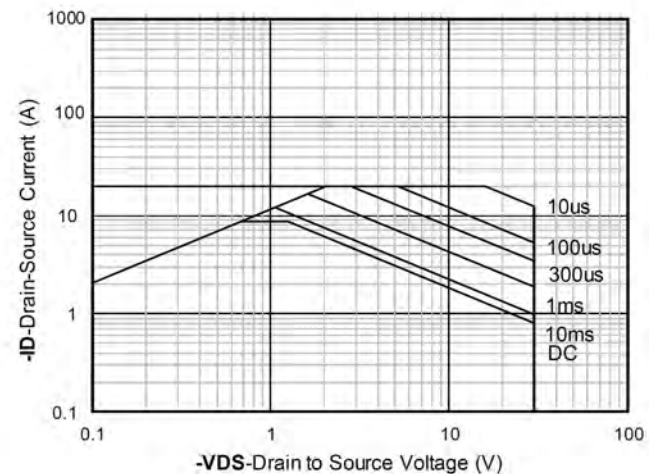
Normalized breakdown voltage



Normalized Threshold voltage

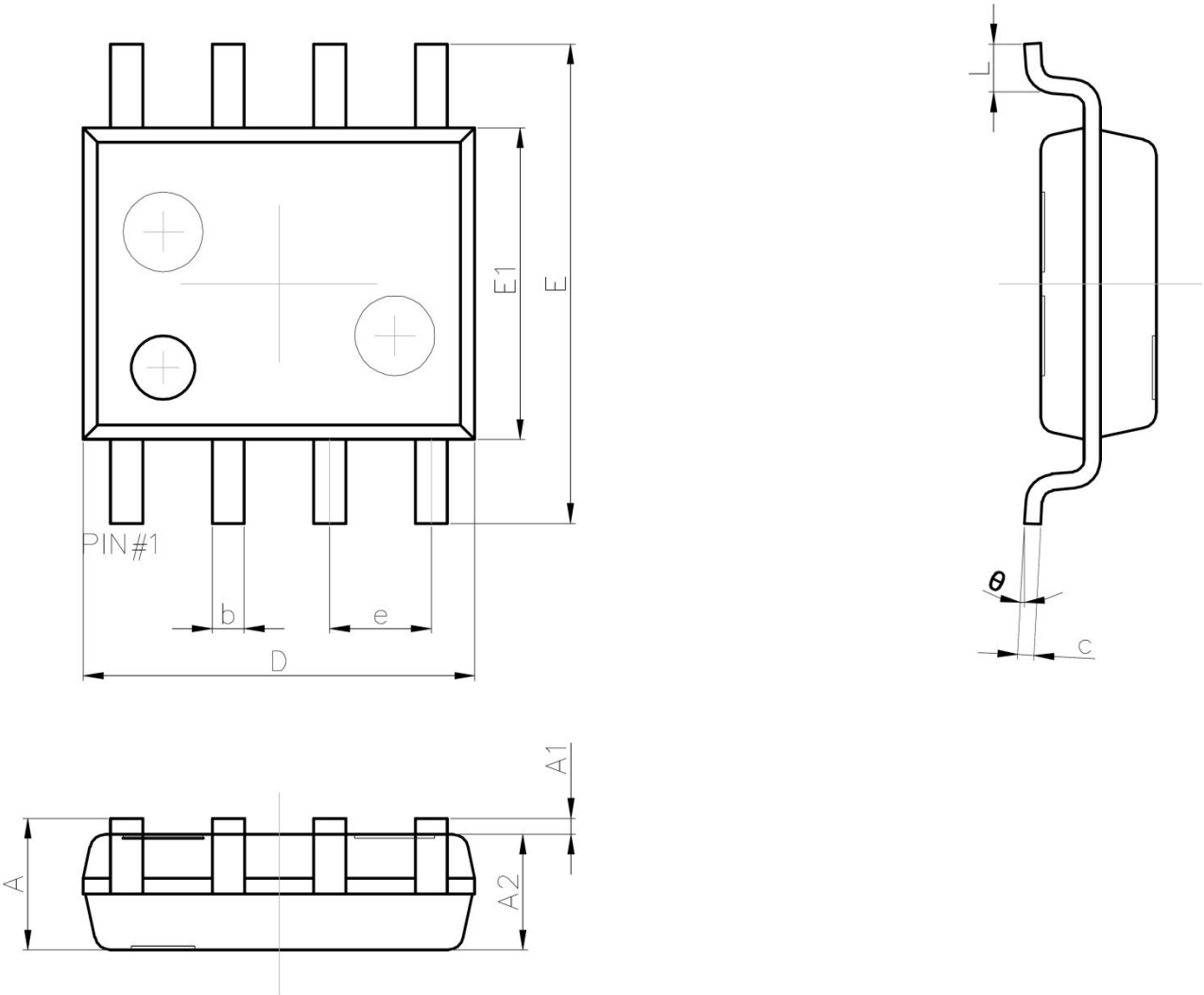


Maximum Transient Thermal Impedance



Safe Operation Area

SOP-8L Package Information



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	1.35	1.75
A1	0.10	0.25
A2	1.35	1.55
b	0.33	0.51
c	0.17	0.25
D	4.80	5.00
e	1.27 REF.	
E	5.80	6.20
E1	3.80	4.00
L	0.40	1.27
θ	0°	8°

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